Upgraded Bunch-Arrival-Time Monitors for the European XFEL Reaching Below 3fs Time Resolution

First Results Evaluating the BAM Performance and Jitter Behaviour of the Electron Bunches.

Marie K. Czwalinna, (DESY) On behalf of the Special Diagnostics team, and many others.

IBIC 2019, Malmoe, Sweden



HELMHOLTZ RESEARCH FOR GRAND CHALLENGES

Facility & Infrastructure

- Optical Synchronisation System
- Locations of Arrival Monitors



By courtesy of Jost Mueller, representing the Laser-based Synchronisation team, DESY MSK.

Optical Synchronisation System at EuXFEL

Free-Electron Laser Facility, 3.5km

World-wide Unique Large-Scale 24/7 Operation



Injector LINAC BC0 <mark>—</mark> L1 <mark>—</mark> BC1 -L2 L3 GUN-– BC2 – A1 AH1 RF BA№ BAM BAM **Optical Clock Sub Distribution RF Clock** MLO SLO MO up to 24 x LSU up to 20 x LSU

optical reference distributed via length-stabilized optical fiber links and used for

- □ **laser locking** (injector, pump-probe, ...)
- □ RF re-synchronization (**REFM-OPT**)
- □ bunch arrival time diagnostics (**BAM**)

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Optical Synchronisation System at EuXFEL

Point-to-Point Stability MO \rightarrow **Pump-Probe Laser**



Technical Concept

Improvements

Bunch Arrival Monitor (BAM)



Bunch Arrival Monitor (BAM)



Electro-Optical Modulator

Choice of Electro-Optical Modulator:

Compromise between RF bandwidth, $V\pi$ & optical properties

Electro-Optic Modulator (commercial) - 33GHz bandwidth $V\pi$ typically 3.8V to 4.3V

Transfers RF phase changes into amplitude changes of a laser signal.





Choice of Electro-Optical Modulator:

Compromise between RF bandwidth, $V\pi$ & optical properties

LiNbO3

Good 🗾

RF Phase of Voltage

Bad

- +/- $V\pi$ 3.8V to 4.5V, typically
- + uniform E/O coefficients in laser bandwidth
- + high damage voltage damage threshold

Semiconductors

- + Small Vπ
- Large wavelength dependence of E/O coefficients
- Large wavelength dependence of Vπ





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Voltage

Electro-Optical Modulation with BAM Signal



Voltage signal @ 250pC

- Calculated from a small signal response (deconvolution)
- □ Measurement of modulation @ 6pC depicts actual voltage signal



Electro-Optical Modulation with BAM Signal







Nonlinearities in the RF Chain





Limiter response

RF Limiter (PIN diode), drawbacks

Semiconductor with AM-to-PM effect (\rightarrow falsely detected timing change)

Signal distortion due to limited response time of EOM

& Non-Linearity from non-ideal transmission curve

https://www.everythingrf.com/community/what-is-an-rf-limiter

Nonlinearities in the RF Chain



https://www.everythingrf.com/community/what-is-an-rf-limiter



RF & EO part optimised



No distortions in modulation signal anymore

With larger the voltage increasing slope steepness

But, with larger voltage,

- Decreasing dynamic range
- Decreasing modulation depth:
 - □ Finite laser pulse width (1.5s to 2ps)
 - D Phase slippage between RF and laser group velocity



Technical Concept

Performance Evaluation

Sensitivity of arrival time detection & its charge calibration



Sensitivity of arrival time detection & its charge calibration



Laser pulse train readout & procession in FPGA (high-pass filter scheme).







Laser pulse train readout & procession in FPGA





First Results

Accuracy of Arrival Time Measurements

BAM: Measurement Accuracy

Whole detection chain from Optical Synchronisation to BAM system



Pulsed operation (RF ~ 1ms, 10Hz)

- □ 27000 / sec
- e- bunches 220ns spaced
- □ 100ms separation

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Mean value over 200 bunches per train, 600 trains (1min.)









Summary & Outlook

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High Precision Arrival Time Measurement → Longitudinal Intra-Train Feedback as Perspective

□ BAMs with single shot resolution of <3fs @250pC

□ Correlation between equivalent BAMs \rightarrow Synchronisation level \approx 1.2fs rms

□ Suppressing low frequency noise up to 25kHz from pulse to pulse jitter using an intra-train beam-based FB to reach 4fs rms stability is within realms of possibility





Summary



Involved people :



(without any claim to completeness)

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Bioern Lautenschlager (DESY)



TECHNISCHE HOCHSCHULE MITTELHESSEN



RF Design: Aleksandar Angelovski (formerly at TU Darmstadt),

Cezary Sydlo (now PSI)

Beamline Components: Silke Vilcins-Czvitkovits, Maximilian Holz (DESY)

Firmware/Software: Lukasz Butkowski. Martin Killenberg, Jens Georg (DESY), Michele Viti (formerly at DESY), PAUL SCHERRER INSTITUT

Radoslav Rybaniek (now PSI)

Electronic Hardware: Konrad Przygoda, Michael Fenner (DESY)

Andreas Penirschke (now THM)

